# INA6017AM1-TH50

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE

AEC-Q101 Compliance

## **DESCRIPTION**

INA6017AM1 is a silicon PNP transistor.

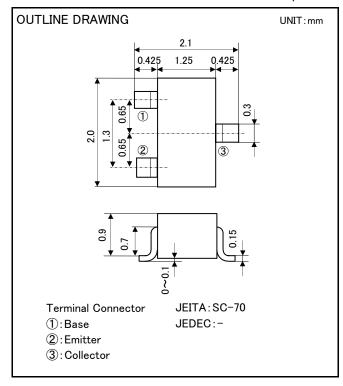
It is designed with high voltage.

## **FEATURE**

- ·Small package for easy mounting.
- •High voltage  $V_{CEO} = -150V$
- •Low voltage VCE(sat) = −0.2V(MAX)

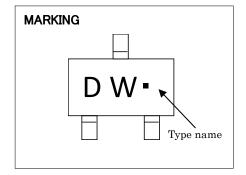
## **APPLICATION**

High voltage switching.



## MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING	UNIT
V <sub>CBO</sub>	Collector to Base voltage	-160	V
$V_{EBO}$	Emitter to Base voltage	-5	V
$V_{CEO}$	Collector to Emitter voltage	-150	V
I <sub>CM</sub>	Peak collector current	-200	mA
Ιc	Collector current	-100	mA
P <sub>c</sub>	Collector dissipation(Ta=25°C)	200	mW
$T_{j}$	Junction temperature	+150	°C
$T_{stg}$	Storage temperature	-55 <b>~</b> +150	°C



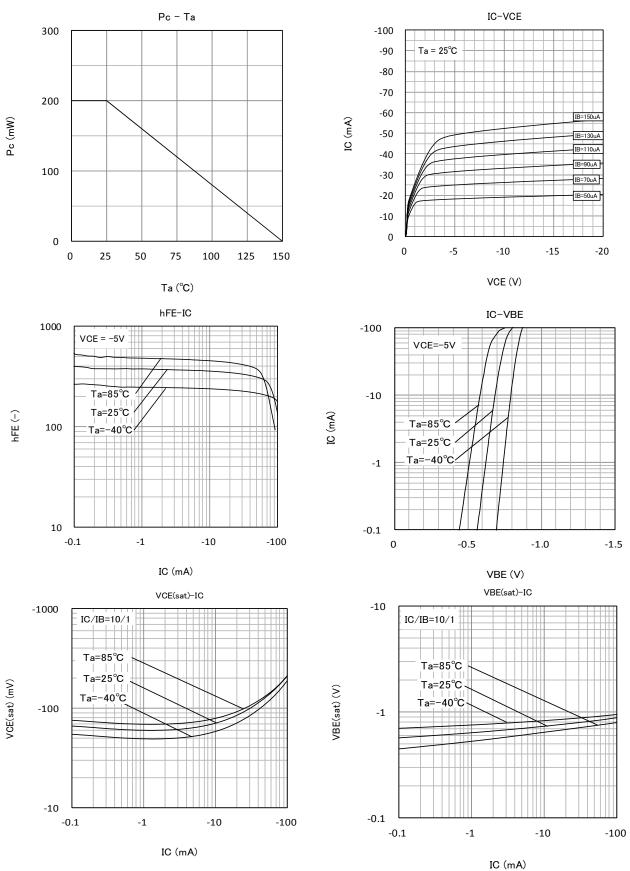
## ELECTRICAL CHARACTERISTICS (Ta=25°C)

LIMITO									
SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT			
			MIN	TYP	MAX	51411			
V <sub>(BR)CBO</sub>	C to B breakdown voltage	I <sub>c</sub> =-100uA, I <sub>E</sub> =0	-160	ı	ı	V			
V <sub>(BR)EBO</sub>	E to B breakdown voltage	$I_{E}$ =-10uA, $I_{C}$ =0	-5	1	-	V			
V <sub>(BR)CEO</sub>	C to E breakdown voltage	I <sub>C</sub> =-1mA, R <sub>BE</sub> =∞	-150	-	-	V			
I <sub>CBO</sub>	Collector cut off current	$V_{CB}$ =-120V, $I_E$ =0	-	_	-100	nA			
I <sub>EBO</sub>	Emitter cut off current	$V_{EB}$ =-3V, I $_{C}$ =0	-	-	-100	nA			
hFE1	DC forward current gain1	VCE=-5V, I <sub>c</sub> =-1mA	150	_	-	-			
hFE2	DC forward current gain2	VCE=-5V, I <sub>c</sub> =-10mA	200	-	500	-			
hFE3	DC forward current gain3	VCE=-5V, I $_{\rm c}$ =-50mA	45	_	-	-			
VCE(sat)	C to E saturation voltage	I <sub>c</sub> =-10mA, I <sub>B</sub> =-1mA	-	-	-0.2	V			
VBE(sat)	B to E saturation voltage	I <sub>c</sub> =-10mA, I <sub>B</sub> =-1mA	-	-	-1.0	٧			
fT	Gain bandwidth product	VCE=-10V, I <sub>E</sub> =10mA	-	130	-	MHz			
Cob	Collector output capacitance	VCB=-10V, I <sub>E</sub> =0, f=1MHz	-	3	-	pF			

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## TYPICAL CHARACTERISTICS





## Keep safety first in your circuit designs!

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